74AHC74; 74AHCT74

Dual D-type flip-flop with set and reset; positive-edge trigger

Rev. 8 — 22 April 2020 Product data sheet

1. General description

The 74AHC74; 74AHCT74 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC74; 74AHCT74 is a dual positive-edge triggered, D-type flip-flop with individual data inputs (D), clock inputs (CP), set inputs (\overline{SD}) and reset inputs (\overline{RD}). It also has complementary outputs (Q and \overline{Q}).

The set and reset are asynchronous active LOW inputs that operate independent of the clock input. Information on the data input is transferred to the Q output on the LOW to HIGH transition of the clock pulse. The data inputs must be stable one set-up time prior to the LOW to HIGH clock transition for predictable operation.

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

2. Features and benefits

- · Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - For 74AHC74: CMOS level
 - For 74AHCT74: TTL level
- ESD protection:
 - HBM EIA/JESD22-A114E exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V
 - CDM EIA/JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

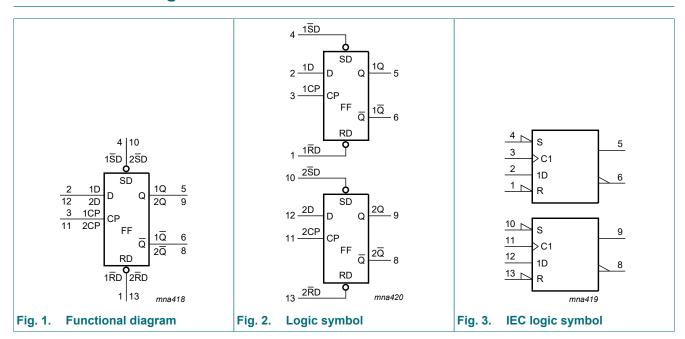
3. Ordering information

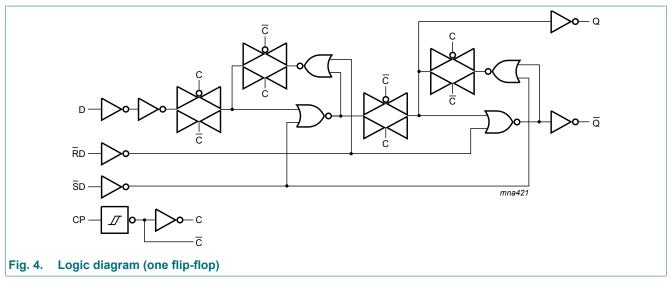
Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74AHC74D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	SOT108-1	
74AHCT74D			body width 3.9 mm		
74AHC74PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1	
74AHCT74PW			body width 4.4 mm		
74AHC74BQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	SOT762-1	
74AHCT74BQ			very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm		



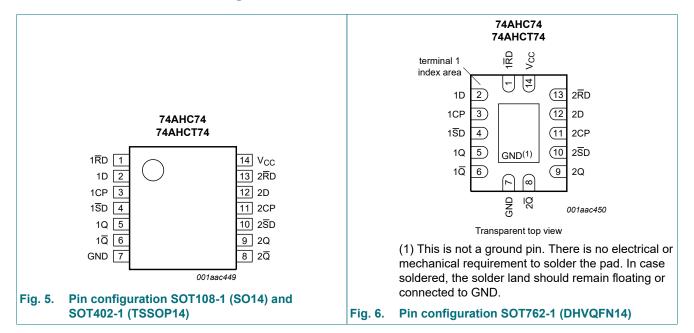
4. Functional diagram





5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1RD	1	asynchronous reset direct input (active LOW)
1D	2	data input
1CP	3	clock input (LOW to HIGH, edge-triggered)
1SD	4	asynchronous set direct input (active LOW)
1Q	5	true flip-flop output
1Q	6	complement flip-flop output
GND	7	ground (0 V)
2Q	8	complement flip-flop output
2Q	9	true flip-flop output
2SD	10	asynchronous set direct input (active LOW)
2CP	11	clock input (LOW to HIGH, edge-triggered)
2D	12	data input
2RD	13	asynchronous reset direct input (active LOW)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care;

 \uparrow = LOW to HIGH transition; Q_{n+1} = state after the next LOW to HIGH CP transition.

Control			Input	Output							
nSD	nRD	nCP	nD	nQ	nQ	nQ _{n+1}	$n\overline{Q}_{n+1}$				
L	Н	X	X	Н	L	-	-				
Н	L	X	Х	L	Н	-	-				
L	L	Х	Х	Н	Н	-	-				
Н	Н	1	L	-	-	L	Н				
Н	Н	1	Н	-	-	Н	L				

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	[1]	-20	-	mA
I _{OK}	output clamping current	V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V	[1]	-20	+20	mA
Io	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-25	+25	mA
I _{CC}	supply current			-	+75	mA
I _{GND}	ground current			-75	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	7	74AHC7	4	7	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 3.0 V to 3.6 V	-	-	100	-	-	-	ns/V
		V _{CC} = 4.5 V to 5.5 V	-	-	20	-	-	20	ns/V

^[2] For SOT108-1 (SO14) package: P_{tot} derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P_{tot} derates linearly with 7.3 mW/K above 81 °C. For SOT762-1 (DHVQFN14) package: P_{tot} derates linearly with 9.6 mW/K above 98 °C.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

74AHC7	Parameter	Conditions		25 °C		-	°C to 5 °C	-40 ° +12	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
74AHC7	4		_							
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level	Conditions $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 5.5 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 5.5 \text{ V}$ $V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{0} = -50 \text{ μA; } V_{CC} = 2.0 \text{ V}$ $I_{0} = -50 \text{ μA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = -50 \text{ μA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = -8.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = -8.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$ $V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{0} = 50 \text{ μA; } V_{CC} = 2.0 \text{ V}$ $I_{0} = 50 \text{ μA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = 50 \text{ μA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = 4.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = 8.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{0} = 8.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND; } I_{0} = 0 \text{ A; }$ $V_{CC} = 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND; } I_{0} = 0 \text{ A; }$ $V_{CC} = 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$ $I_{0} = -50 \text{ μA}$ $I_{0} = -50 \text{ μA}$ $I_{0} = -8.0 \text{ mA}$	-	-	0.5	-	0.5	-	0.5	V
	input voltage $\begin{aligned} &V_{CC}=3.0 \text{ V} \\ &V_{CC}=5.5 \text{ V} \end{aligned}$ $\begin{aligned} &HIGH\text{-level} & V_I=V_{IH} \text{ or } V_{IL} \\ &I_O=-50 \mu\text{A; } V_{CC}=2.0 \text{ V} \\ &I_O=-50 \mu\text{A; } V_{CC}=3.0 \text{ V} \\ &I_O=-50 \mu\text{A; } V_{CC}=3.0 \text{ V} \end{aligned}$ $I_O=-6.0 m\text{A; } V_{CC}=3.0 \text{ V} \\ &I_O=-8.0 m\text{A; } V_{CC}=4.5 \text{ V} \end{aligned}$ $I_O=-8.0 m\text{A; } V_{CC}=4.5 \text{ V} \end{aligned}$ $I_O=-8.0 m\text{A; } V_{CC}=4.5 \text{ V} \end{aligned}$ $I_O=-8.0 m\text{A; } V_{CC}=4.5 \text{ V} \end{aligned}$	-	-	0.9	-	0.9	-	0.9	V	
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}		$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 5.5 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 3.0 \text{ V}$ $V_{CC} = 5.5 \text{ V}$ $V_{IO} = -50 \text{ µA; } V_{CC} = 2.0 \text{ V}$ $I_{O} = -50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = -50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = -4.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = -8.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = -8.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = 50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = 50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = 50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = 50 \text{ µA; } V_{CC} = 3.0 \text{ V}$ $I_{O} = 8.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$ $I_{O} = 8.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$ $I_{O} = 8.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$ ent $V_{I} = V_{CC} \text{ or GND; } I_{O} = 0 \text{ A; }$ $V_{CC} = 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ end $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{IH} \text{ or } V_{IL; } V_{CC} = 4.5 \text{ V}$ $I_{O} = -50 \text{ µA}$ $I_{O} = -50 \text{ µA}$ $I_{O} = -50 \text{ µA}$	$V_{I} = V_{IH} \text{ or } V_{IL}$							
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		I_{O} = -8.0 mA; V_{CC} = 4.5 V	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
l _l	input leakage current		-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current		-	-	2.0	-	20	-	40	μΑ
C _I	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	10	pF
74AHCT	74			·		•	'	'	'	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	Ι _Ο = -50 μΑ	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V _{OL}										
			-	0	0.1	-	0.1	-	0.1	٧
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	٧
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	20	-	40	μΑ

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 ° +12	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other pins at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	10	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 9.

f _{max} n fi	Parameter	Conditions		25 °C			°C to 5 °C	-40 ° +12	Unit	
			Min	Typ [1]	Max	Min	Max	Min	Max	
74AHC7	4					•		•		•
t _{pd}	1	nCP to nQ, $n\overline{Q}$; see Fig. 7 [2]								
	delay	V _{CC} = 3.0 V to 3.6 V; C _L = 15 pF	-	5.2	11.9	1.0	14.0	1.0	15.0	ns
		V_{CC} = 3.0 V to 3.6 V; C_L = 50 pF	-	7.4	15.4	1.0	17.5	1.0	19.5	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.7	7.3	1.0	8.5	1.0	9.5	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	5.2	9.3	1.0	10.5	1.0	12.0	ns
		nSD, nRD to nQ, nQ; see Fig. 8								
		V _{CC} = 3.0 V to 3.6 V; C _L = 15 pF	-	5.4	12.3	1.0	14.5	1.0	15.5	ns
		V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF	-	7.7	15.8	1.0	18.0	1.0	20.0	ns
			-	3.7	7.7	1.0	9.0	1.0	10.0	ns
		V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	5.3	9.7	1.0	11.0	1.0	12.5	ns
f _{max}	maximum frequency	see Fig. 7								
		V _{CC} = 3.0 V to 3.6 V; C _L = 15 pF	80	125	-	70	-	70	-	MHz
		V _{CC} = 3.0 V to 3.6 V; C _L = 50 pF	50	75	-	45	-	45	-	MHz
		V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF	130	170	-	110	-	110	-	MHz
		V _{CC} = 4.5 V to 5.5 V; C _L = 50 pF	90	115	-	75	-	75	-	MHz
t _W	pulse width	CP HIGH or LOW; nSD, nRD LOW; see Fig. 7 and Fig. 8								
		V _{CC} = 3.0 V to 3.6 V	6.0	-	-	7.0	-	7.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	nD to nCP; see Fig. 7								
		V _{CC} = 3.0 V to 3.6 V	6.0	-	-	7.0	-	7.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	nD to nCP; see Fig. 7								
		V _{CC} = 3.0 V to 3.6 V	0.5	-	-	0.5	-	0.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	-	-	0.5	-	0.5	-	ns

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 ' +12	Unit	
			Min	Typ [1]	Max	Min	Max	Min	Max	-
t _{rec}	recovery	nRD to nCP; see Fig. 8								
	time	V _{CC} = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	3.0	-	-	3.0	-	3.0	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{CC}$ [3]	-	12	-	-	-	-	-	pF
74AHCT	74									
t _{pd}		nCP to nQ, $n\overline{Q}$; see Fig. 7 [2]								
	delay	V_{CC} = 4.5 V to 5.5 V; C_L = 15 pF	-	3.3	7.8	1.0	9.0	1.0	10.0	ns
		V_{CC} = 4.5 V to 5.5 V; C_L = 50 pF	-	4.8	8.8	1.0	10.0	1.0	11.0	ns
		nSD, nRD to nQ, nQ; see Fig. 8								
		V _{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.7	10.4	1.0	12.0	1.0	13.0	ns
		V_{CC} = 4.5 V to 5.5 V; C_L = 50 pF	-	5.3	11.4	1.0	13.0	1.0	14.5	ns
f _{max}	maximum	see Fig. 7								
	frequency	V_{CC} = 4.5 V to 5.5 V; C_L = 15 pF	100	160	-	80	-	80	-	MHz
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V; } C_L = 50 \text{ pF}$	80	140	-	65	-	65	-	MHz
t _W	pulse width	CP HIGH or LOW; $n\overline{S}D$, $n\overline{R}D$ LOW; V_{CC} = 4.5 V to 5.5 V; see Fig. 7 and Fig. 8	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	nD to nCP; V_{CC} = 4.5 V to 5.5 V; see Fig. 7	5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	nD to nCP; V_{CC} = 4.5 V to 5.5 V; see Fig. 7	0	-	-	0	-	0	-	ns
t _{rec}	recovery time	nRD to nCP; V_{CC} = 4.5 V to 5.5 V; see Fig. 8	3.5	-	-	3.5	-	3.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{CC}$ [3]	-	16	-	-	-	-	-	pF

- Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

10.1. Waveforms

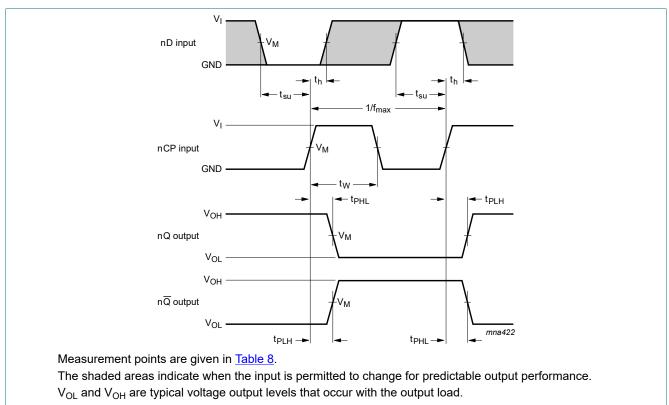


Fig. 7. Clock pulse width, maximum frequency, set-up times, hold times and input to output propagation delays

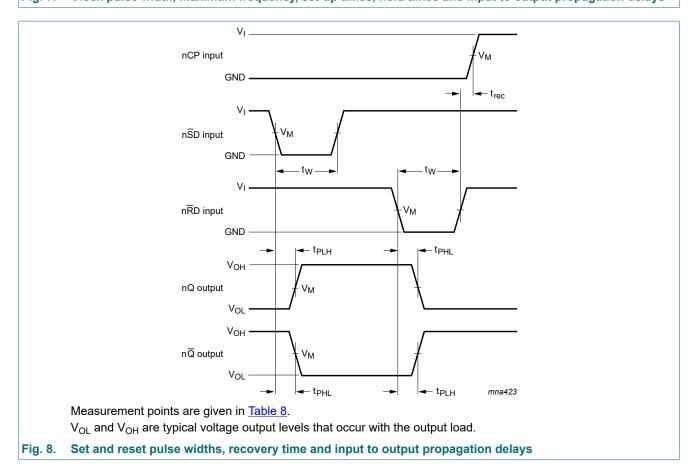
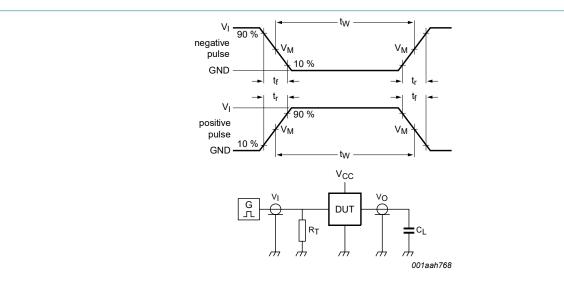


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74AHC74	0.5 × V _{CC}	0.5 × V _{CC}
74AHCT74	1.5 V	0.5 × V _{CC}



For test data, see Table 9.

Definitions for test circuit:

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

Fig. 9. Test circuit for measuring switching times

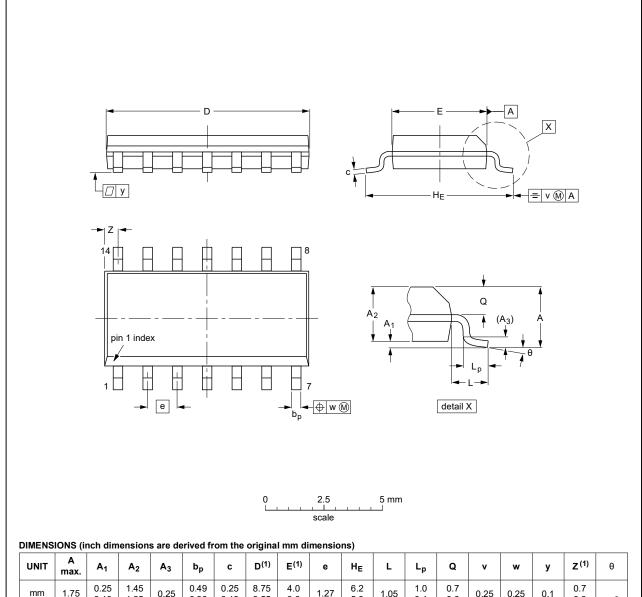
Table 9. Test data

Туре	Input		Load	Test
	V _I	t _r , t _f C _L		
74AHC74	V _{CC}	≤ 3.0 ns	50 pF, 15 pF	t _{PLH} , t _{PHL}
74AHCT74	3.0 V	≤ 3.0 ns	50 pF, 15 pF	t _{PLH} , t _{PHL}

11. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



ι	JNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
	mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
in	ches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

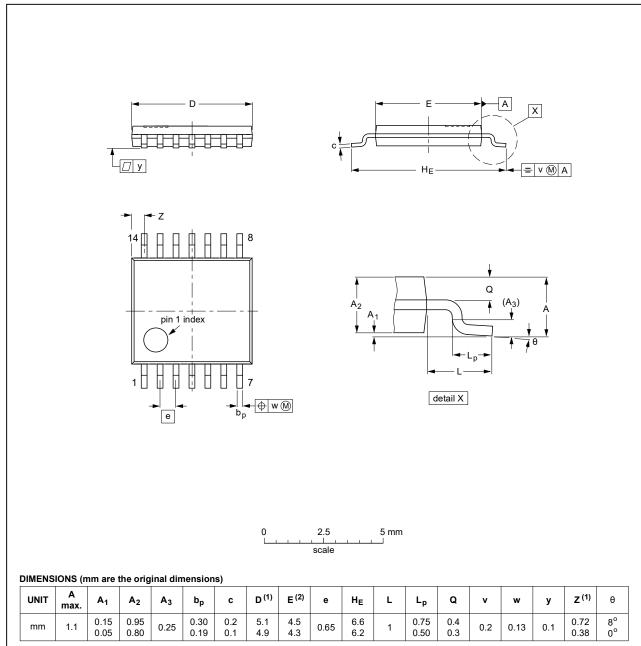
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig. 10. Package outline SOT108-1 (SO14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT402-1		MO-153				99-12-27 03-02-18

Fig. 11. Package outline SOT402-1 (TSSOP14)

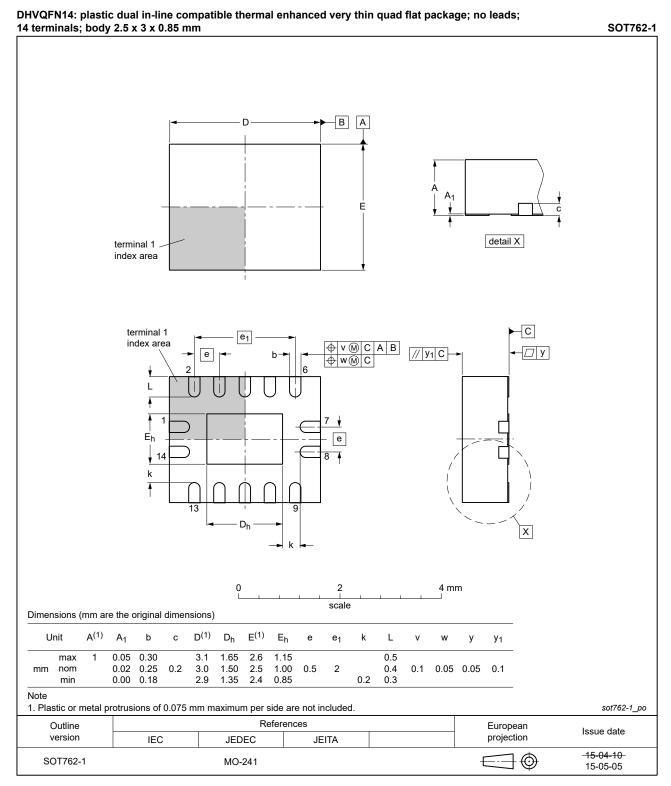


Fig. 12. Package outline SOT762-1 (DHVQFN14)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
CMOS	Complementary Metal-Oxide Semiconductor	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
LSTTL	Low-power Schottky Transistor-Transistor Logic	
MM	Machine Model	

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT74 v.8	20200422	Product data sheet	-	74AHC_AHCT74 v.7
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 5.1: Corrected pin configuration drawings (errata). Table 4: Derating values for P_{tot} total power dissipation updated. Fig. 12: Package outline drawing SOT762-1 (DHVQFN14) updated. 			
74AHC_AHCT74 v.7	20150421	Product data sheet	-	74AHC_AHCT74 v.6
Modifications:	• <u>Table 7</u> : minimum f _{max} values at 3.0 V to 3.6 V for 74AHC74 corrected (errata).			
74AHC_AHCT74 v.6	20141020	Product data sheet	-	74AHC_AHCT74 v.5
Modifications:	<u>Table 3</u> corrected (errata).			
74AHC_AHCT74 v.5	20080609	Product data sheet	-	74AHC_AHCT74 v.4
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Table 6: the conditions for input leakage current have been changed. 			
74AHC_AHCT74 v.4	20050207	Product data sheet	-	74AHC_AHCT74 v.3
74AHC_AHCT74 v.3	20040429	Product specification	-	74AHC_AHCT74 v.2
74AHC_AHCT74 v.2	19990923	Product specification	-	74AHC_AHCT74 v.1
74AHC_AHCT74 v.1	19990805	Product specification	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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